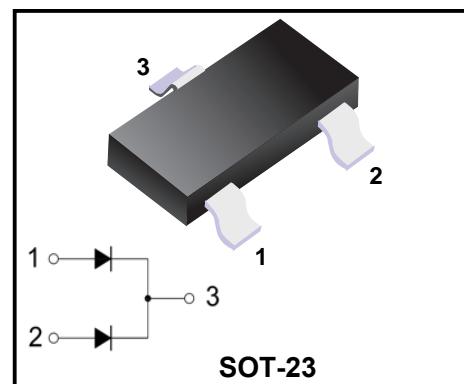


■ Switching Diodes

Features

- Small plastic SMD package.
- High switching sped: max.4 ns.
- Repetitive peak forward current: max.450 mA.



Marking Code	
BAV70	A4

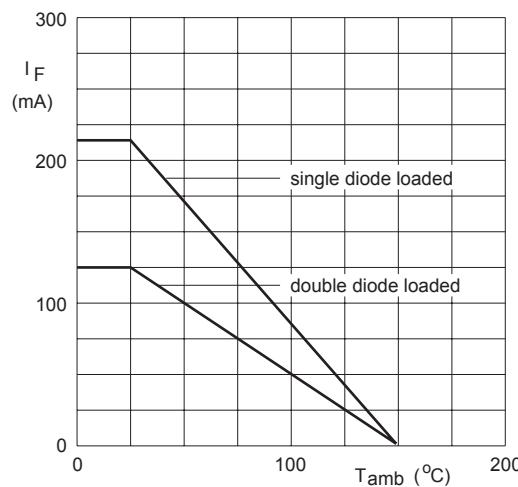
Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V _R _{RM}	85	V
Continuous reverse voltage	V _R	75	V
Continuous forward current(single diode loaded *) (double diode loaded *)	I _F	215 125	mA
Repetitive peak forward current	I _F _{RM}	450	mA
Non-repetitive peak forward current T _j =25 °C t=1 μ s t=1ms t=1s	I _F _{SM}	4 1 0.5	A
power dissipation *	P _D	250	mW
Thermal resistance from junction to tie-point	R _{th j-tp}	360	K/W
Thermal resistance from junction to ambient *	R _{th j-a}	500	K/W
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

* Device mounted on an FR4 printed-circuit board.

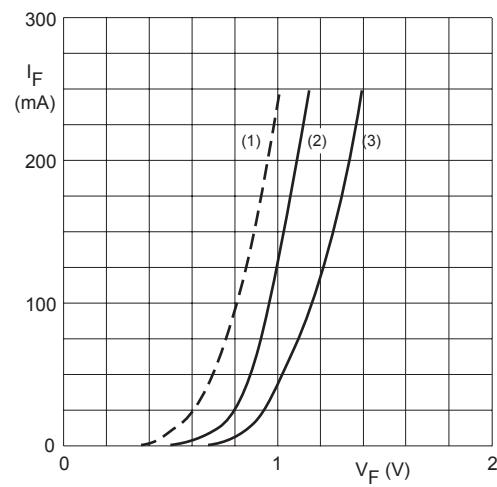
Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Test conditions	Max	Unit
Forward voltage	V _F	I _F =1 mA	715	mV
		I _F =10 mA	855	mV
		I _F =50 mA	1	V
		I _F =150 mA	1.25	V
Reverse current	I _R	V _R =75 V	1	
		V _R =25 V; T _j = 150 °C	30	μ A
		V _R =75 V; T _j = 150 °C	50	
Diode capacitance	C _d	V _R =0 V, f= 1 MHz	1.5	pF
Reverse recovery time	t _{rr}	when switched from I _F = 10 mA to I _R =10mA;R _L =100 Ω ; measured at I _R = 1mA	4	nS
Forward recovery voltage	V _{fr}	I _F = 10 mA, t _r = 20 ns	1.75	V

Typical Characteristic


Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.

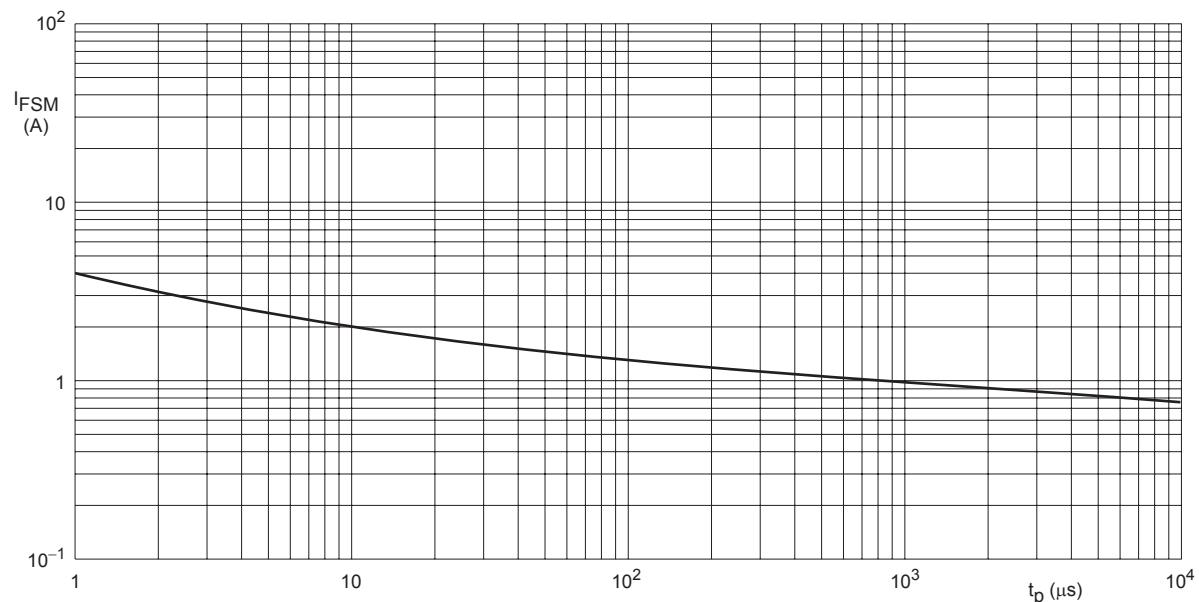


(1) $T_j = 150 \text{ }^\circ\text{C}$; typical values.

(2) $T_j = 25 \text{ }^\circ\text{C}$; typical values.

(3) $T_j = 25 \text{ }^\circ\text{C}$; maximum values.

Fig.3 Forward current as a function of forward voltage.



Based on square wave currents.
 $T_j = 25 \text{ }^\circ\text{C}$ prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

Typical Characteristic

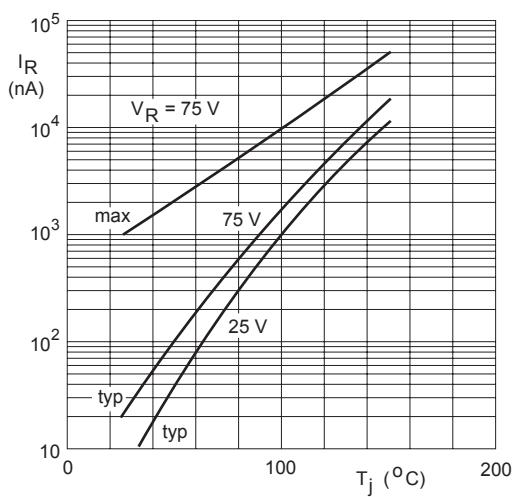
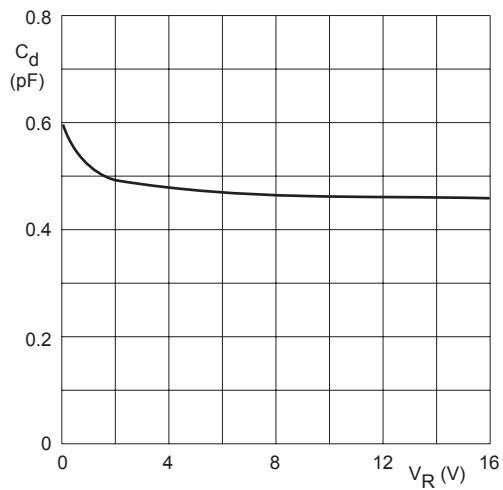


Fig.5 Reverse current as a function of junction temperature.



$f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C}$.

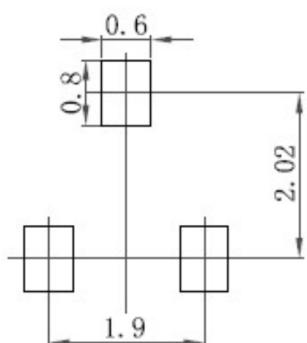
Fig.6 Diode capacitance as a function of reverse voltage; typical values.

Ordering information

Package	Packing Description	Base Quantity	Packing Quantity
SOT-23	Tape/Reel,7"reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

Package Dimensions
SOT-23

Dim.	Millimeter (mm)		mil	
	Min.	Max.	Min.	Max.
A	0.9	1.15	35	45
A1	0.1		3.9	
bp	0.38	0.48	15	19
C	0.09	0.15	3.54	5.9
D	2.8	3.0	110	118
E	1.2	1.4	47	55
E	1.9		75	
E1	0.95		37	
HE	2.1	2.55	83	100
Lp	0.15	0.45	5.9	18
Q	0.45	0.55	18	22
V	0.2		7.9	
W	0.1		4	

The recommended mounting pad size


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